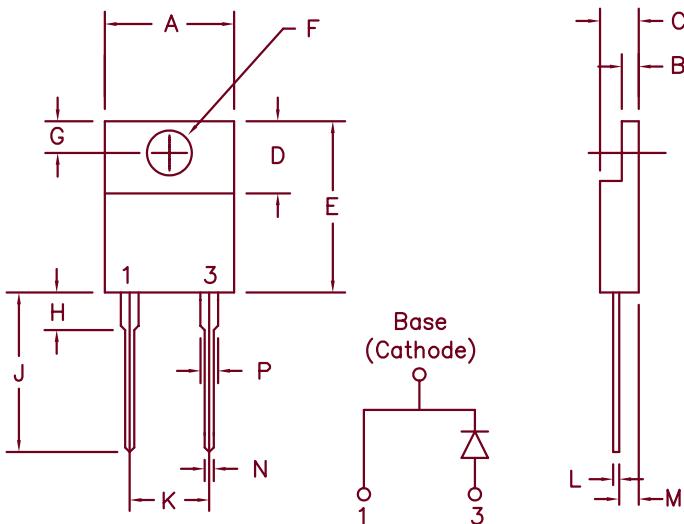


10 Amp Schottky Barrier Rectifiers

MS1005, MS1006



Dim.	Inches		Millimeter		Notes
	Minimum	Maximum	Minimum	Maximum	
A	.390	.415	9.91	10.54	
B	.045	.055	1.14	1.40	
C	.180	.190	4.57	4.83	
D	.245	.260	6.22	6.60	
E	.550	.650	13.97	16.51	
F	.139	.155	3.53	3.94	Dia.
G	.100	.120	2.54	3.05	
H	---	.250	---	6.35	
J	.500	.580	12.70	14.73	
K	.190	.210	4.83	5.33	
L	.014	.025	0.35	0.63	
M	.080	.115	2.03	2.92	
N	.028	.038	0.71	0.96	
P	.045	.055	1.14	1.40	

Similar to TO-220AC

Microsemi Catalog Number	Industry Part Number	Repetitive Peak Reverse Voltage	Transient Peak Reverse Voltage
MS1005	6TQ045 MBR750 MBR10H50	50V	50V
MS1006	USD1060 MBR760 MBR1060 MBR10H60	60V	60V

- Schottky barrier rectifier
- Guard ring protection
- Low power loss, high efficiency
- V_{RRM} 50 to 60 Volts
- Reverse energy tested

Electrical Characteristics

Average Forward Current
Maximum Surge Current
Max. Peak Forward Voltage
Max. Peak Forward Voltage
Max. Peak Reverse Current
Max. Peak Reverse Current
Typical Junction Capacitance

I_{F(AV)} 10 Amps
I_{FSM} 225 Amps
V_{FM} .53 Volts
V_{FM} .67 Volts
I_{RM} 10 mA
I_{RM} 250 μ A
C_J 570 pF

T_C = 158°C, Square wave, R_{θJC} = 2.5°C/W
8.3ms, half sine, T_J = 175°C
I_{FM} = 10A, T_J = 175°C *
I_{FM} = 10A, T_J = 25°C *
V_{RRM}, T_J = 125°C *
V_{RRM}, T_J = 25°C
V_R = 5.0V, T_J = 25°C

*Pulse test: Pulse width 300 μ sec. Duty cycle 2%

Thermal and Mechanical Characteristics

Storage temp range	T _{STG}	-55°C to + 175°C
Operating junction temp range	T _J	-55°C to + 175°C
Max thermal resistance	R _{θJC}	2.5°C/W
Mounting torque		8-12 inch pounds (6-32 screw)
Weight		.08 ounces (2.3 grams) typical

MS1005, MS1006

Figure 1
Typical Forward Characteristics

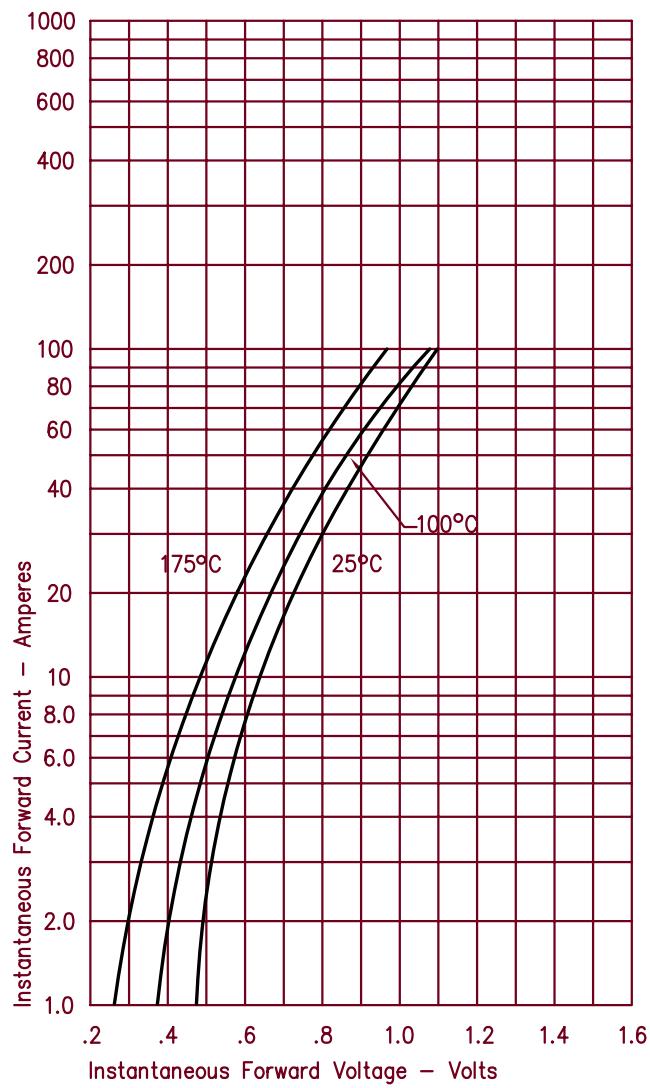


Figure 2
Typical Reverse Characteristics

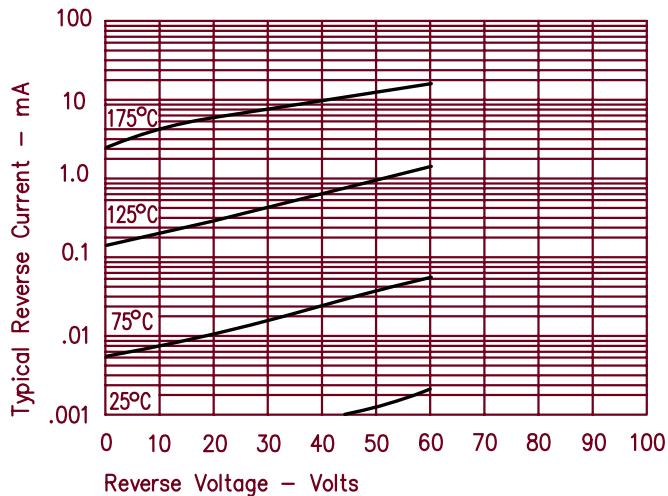


Figure 3
Typical Junction Capacitance

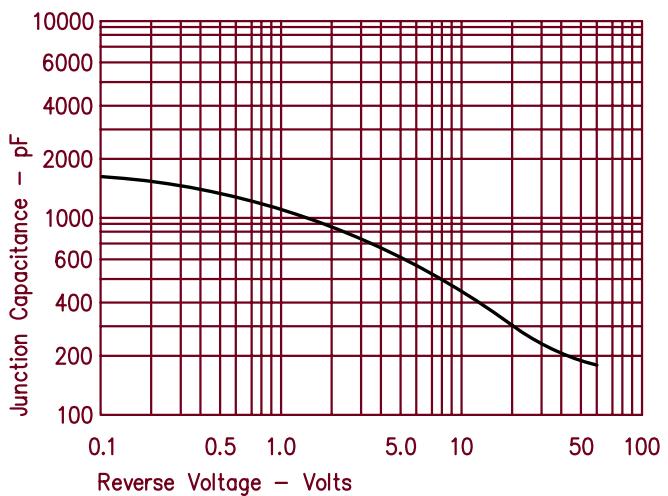


Figure 4
Forward Current Derating

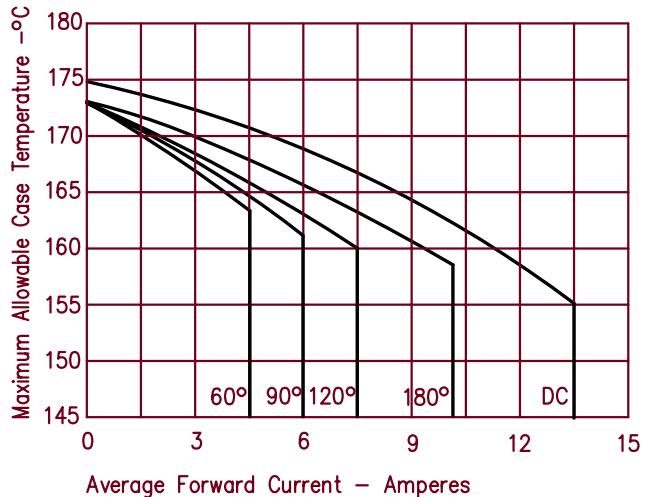


Figure 5
Maximum Forward Power Dissipation

